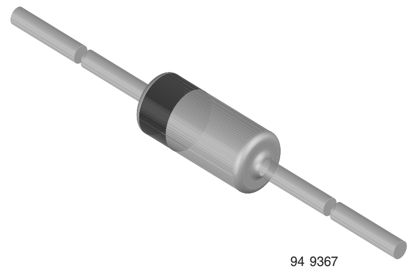
Small Signal Zener Diodes



Features

- Zener voltage specified at 50 µA
- Maximum delta V_Z given from 10 µA to 100 µA
- Very high stability
- Low noise
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

Voltage stabilization

Mechanical Data

Case: DO-35 Glass case
Weight: approx. 125 mg
Packaging codes/options:
TR / 10 k per 13 " reel, 30 k/box
TAP / 10 k per Ammo tape (52 mm tape), 30 k/box

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Power dissipation	l = 4 mm	P_{tot}	500	mW
Z-current		I_Z	P_{tot}/V_Z	mA

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction temperature		T_j	175	°C
Storage temperature range		T_{stg}	- 65 to + 175	°C
Junction ambient	l = 4 mm, T_L = constant	R_{thJA}	300	K/W

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I_F = 100 mA	V_F			1.5	V

Electrical Characteristics

Partnumber [1]	Zener Voltage			Max.Reverse Current	Test Voltage	Max. Zener Current	Max. Voltage Change
	V_Z @ I_Z = 50 μA			I_R [3]	V_R [3]	I_{ZM} [2]	ΔV_Z [4]
	V			μA	V	mA	V
	typ. [1]	min.	max				
1N4678	1.8	1.71	1.89	7.5	1	120	0.70
1N4679	2	1.9	2.1	5	1	110	0.70
1N4680	2.2	2.09	2.31	4	1	100	0.75
1N4681	2.4	2.28	2.52	2	1	95	0.80
1N4682	2.7	2.565	2.835	1	1	90	0.85
1N4683	3	2.85	3.15	0.8	1	85	0.90
1N4684	3.3	3.135	3.465	7.5	1.5	80	0.95
1N4685	3.6	3.42	3.78	7.5	2	75	0.95
1N4686	3.9	3.705	4.095	5	2	70	0.97
1N4687	4.3	4.085	4.515	4	2	65	0.99
1N4688	4.7	4.465	4.935	10	3	60	0.99
1N4689	5.1	4.845	5.355	10	3	55	0.97
1N4690	5.6	5.32	5.88	10	4	50	0.96
1N4691	6.2	5.89	6.51	10	5	45	0.95
1N4692	6.8	6.46	7.14	10	5.1	35	0.90
1N4693	7.5	7.125	7.875	10	5.7	31.8	0.75
1N4694	8.2	7.79	8.61	1	6.2	29	0.5
1N4695	8.7	8.265	9.135	1	6.6	27.4	0.1
1N4696	9.1	8.645	9.555	1	6.9	26.2	0.08
1N4697	10	9.5	10.5	1	7.6	24.8	0.1
1N4698	11	10.45	11.55	0.05	8.4	21.6	0.11
1N4699	12	11.4	12.6	0.05	9.1	20.4	0.12
1N4700	13	12.35	13.65	0.05	9.8	19	0.13
1N4701	14	13.3	14.7	0.05	10.6	17.5	0.14
1N4702	15	14.25	15.75	0.05	11.4	16.3	0.15
1N4703	16	15.2	16.8	0.05	12.1	15.4	0.16
1N4704	17	16.15	17.85	0.05	12.9	14.5	0.17
1N4705	18	17.1	18.9	0.05	13.6	13.2	0.18
1N4706	19	18.05	19.95	0.05	14.4	12.5	0.19
1N4707	20	19	21	0.01	15.2	11.9	0.2
1N4708	22	20.9	23.1	0.01	16.7	10.8	0.22
1N4709	24	22.8	25.2	0.01	18.2	9.9	0.24
1N4710	25	23.75	26.25	0.01	19	9.5	0.25
1N4711	27	25.65	28.35	0.01	20.4	8.8	0.27
1N4712	28	26.6	29.4	0.01	21.2	8.5	0.28
1N4713	30	28.5	31.5	0.01	22.8	7.9	0.3
1N4714	33	31.35	34.65	0.01	25	7.2	0.33
1N4715	36	34.2	37.8	0.01	27.3	6.6	0.36
1N4716	39	37.05	40.95	0.01	29.6	6.1	0.39
1N4717	43	40.85	45.15	0.01	32.6	5.5	0.43

[1] Toleranzing and voltage designation (V_Z). The type numbers shown have a standard tolerance of ± 5 % on the nominal zener voltage.

[2] Maximum zener current ratings (I_{ZM}). Maximum zener current ratings are based on maximum zener voltage of the individual units.

[3] Reverse leakage current (I_R). Reverse leakage currents are guaranteed and measured at V_R as shown on the table.

[4] Maximum voltage change (V_Z). Voltage change is equal to the difference between V_Z at 100 μA and V_Z at 10 μA.

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Typical Characteristics (Tamb = 25 °C unless otherwise specified)

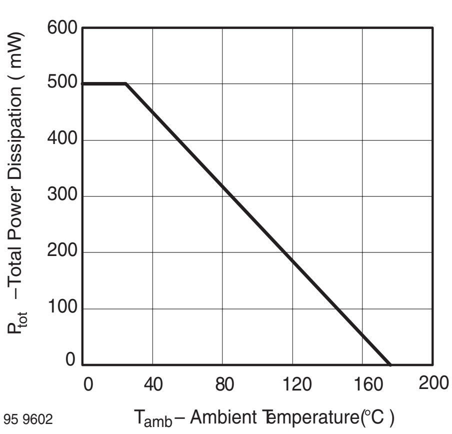


Figure 1. Total Power Dissipation vs. Ambient Temperature

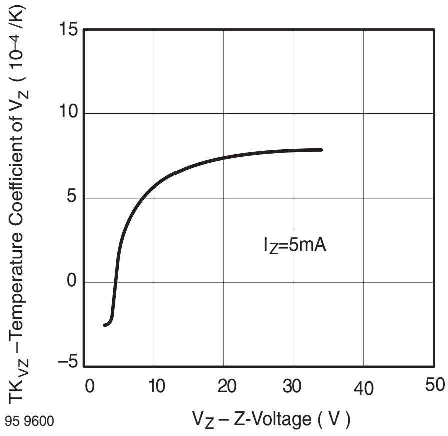


Figure 4. Temperature Coefficient of Vz vs. Z-Voltage

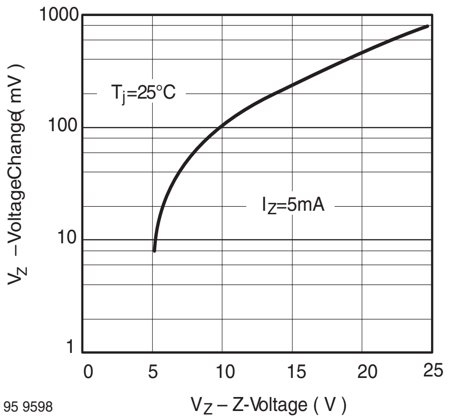


Figure 2. Typical Change of Working Voltage under Operating Conditions at T_{amb}=25°C

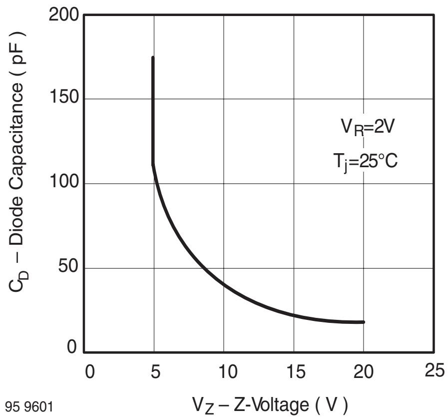


Figure 5. Diode Capacitance vs. Z-Voltage

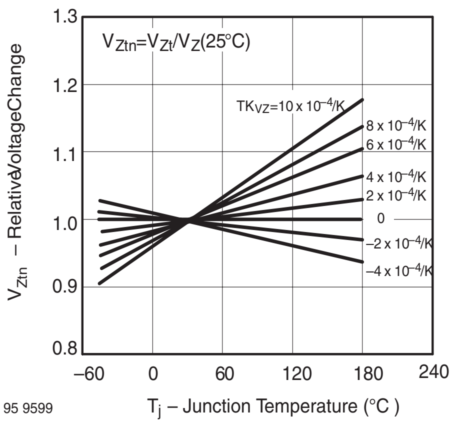


Figure 3. Typical Change of Working Voltage vs. Junction Temperature

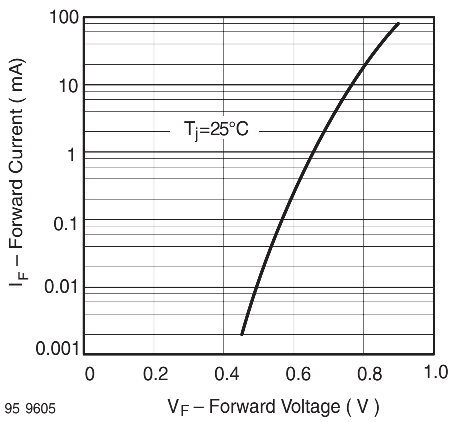


Figure 6. Forward Current vs. Forward Voltage

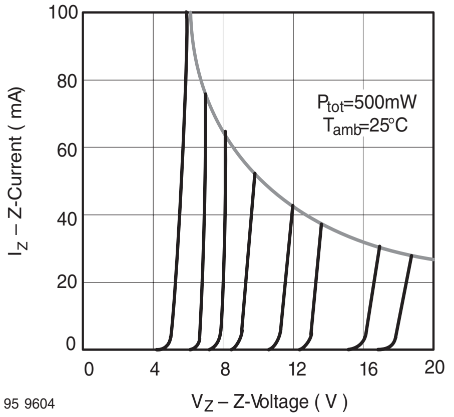


Figure 7. Z-Current vs. Z-Voltage

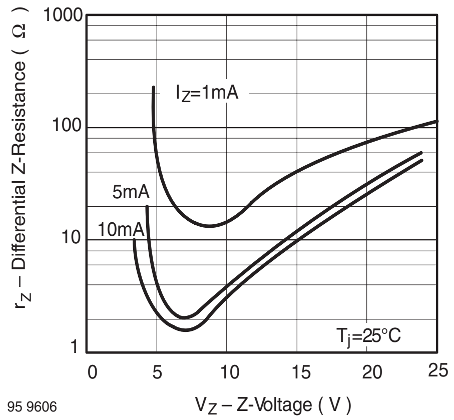


Figure 9. Differential Z-Resistance vs. Z-Voltage

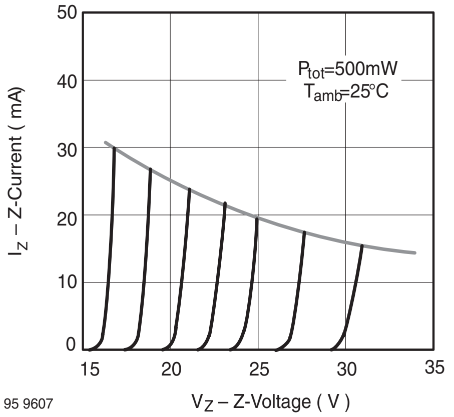


Figure 8. Z-Current vs. Z-Voltage

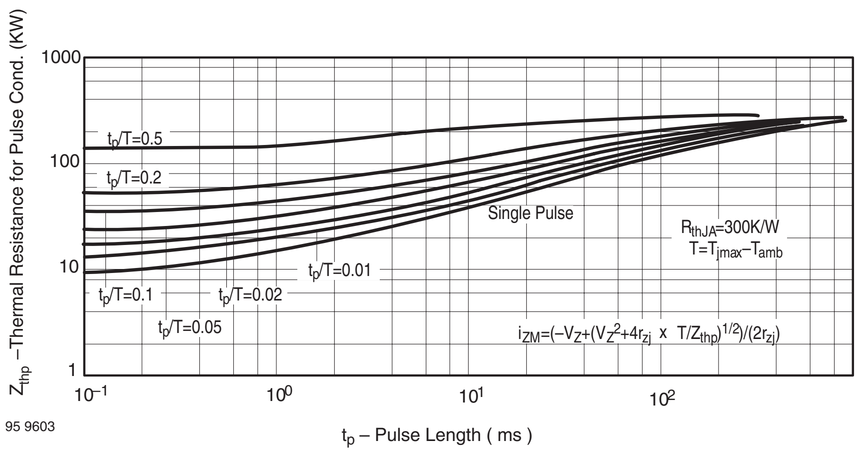
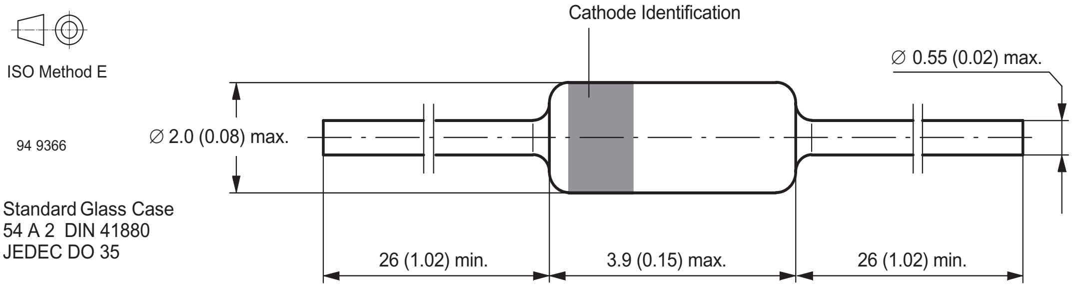


Figure 10. Thermal Response

Package Dimensions in mm (Inches)



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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